National Semiconductor

July 1998

54AC273
Octal D Flip-Flop

General Description

The '273 has eight edge-triggered D-type flip-flops with individual D inputs and Q outputs. The common buffered Clock (CP) and Master Reset ($\overline{MR}$) input load and reset (clear) all flip-flops simultaneously.

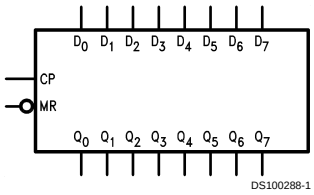
The register is fully edge-triggered. The state of each D input, one setup time before the LOW-to-HIGH clock transition, is transferred to the corresponding flip-flop's Q output.

All outputs will be forced LOW independently of Clock or Data inputs by a LOW voltage level on the $\overline{MR}$ input. The device is useful for applications where the true output only is required and the Clock and Master Reset are common to all storage elements.

Features

- Ideal buffer for microprocessor or memory
- Eight edge-triggered D flip-flops
- Buffered common clock
- Buffered, asynchronous master reset
- See '377 for clock enable version
- See '373 for transparent latch version
- See '374 for TRI-STATE® version
- Outputs source/sink 24 mA
- 'ACT has TTL-compatible inputs
- Standard Military Drawing (SMD)
  — 'AC273: 5962-87756

Logic Symbols



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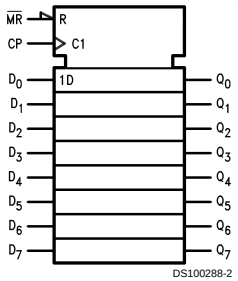
IEEE/IEC



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Pin Names	Description
D_0–D_7	Data Inputs
$\overline{MR}$	Master Reset
CP	Clock Pulse Input
Q_0–Q_7	Data Outputs

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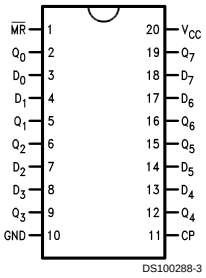
Connection Diagrams

Pin Assignment for DIP and Flatpak



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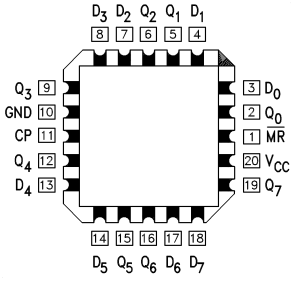
Pin Assignment for LCC



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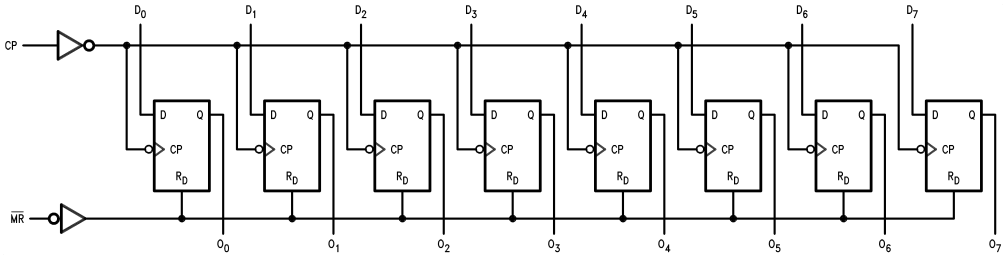
Mode Select-Function Table

Operating Mode	Inputs			Outputs
	$\overline{MR}$	CP	D_n	Q_n
Reset (Clear)	L	X	X	L
Load '1'	H	⌐	H	H
Load '0'	H	⌐	L	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Transition

Logic Diagram



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Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65˚C to +150˚C
Junction Temperature (T_J)	
CDIP	175˚C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
'AC	2.0V to 6.0V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	
54AC	−55˚C to +125˚C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
'AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation of FACT™ circuits outside databook specifications.

DC Characteristics for 'AC Family Devices

Symbol	Parameter	V_{CC} (V)	54AC T_A = −55˚C to +125˚C Guaranteed Limits	Units	Conditions
V_{IH}	Minimum High Level Input Voltage	3.0	2.1	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	3.15		
		5.5	3.85		
V_{IL}	Maximum Low Level Input Voltage	3.0	0.9	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	1.35		
		5.5	1.65		
V_{OH}	Minimum High Level Output Voltage	3.0	2.9	V	I_{OUT} = −50 µA
		4.5	4.4		
		5.5	5.4		
					(Note 2) V_{IN} = V_{IL} or V_{IH}
		3.0	2.4	V	I_{OH} = −12 mA
		4.5	3.7		I_{OH} = −24 mA
		5.5	4.7		I_{OH} = −24 mA
V_{OL}	Maximum Low Level Output Voltage	3.0	0.1	V	I_{OUT} = 50 µA
		4.5	0.1		
		5.5	0.1		
					(Note 2) V_{IN} = V_{IL} or V_{IH}
		3.0	0.50	V	I_{OL} = 12 mA
		4.5	0.50		I_{OL} = 24 mA
		5.5	0.50		I_{OL} = 24 mA
I_{IN}	Maximum Input Leakage Current	5.5	±1.0	µA	V_I = V_{CC}, GND
I_{OLD}	(Note 3) Minimum Dynamic Output Current	5.5	50	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5	−50	mA	V_{OHD} = 3.85V Min

DC Characteristics for 'AC Family Devices (Continued)

Symbol	Parameter	V_{CC} (V)	54AC T_A = −55°C to +125°C Guaranteed Limits	Units	Conditions
I_{CC}	Maximum Quiescent Supply Current	5.5	80.0	µA	$V_{IN} = V_{CC}$ or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}. I_{CC} for 54AC @ 25°C is identical to 74AC @ 25°C.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 5)	54AC T_A = −55°C to +125°C C_L = 50 pF Min	54AC Max	Units	Fig. No.
f_{max}	Maximum Clock Frequency	3.3	75		MHz	
		5.0	90			
t_{PLH}	Propagation Delay Clock to Output	3.3	1.0	15.0	ns	
		5.0	1.0	11.0		
t_{PHL}	Propagation Delay Clock to Output	3.3	1.0	16.0	ns	
		5.0	1.0	11.5		
t_{PHL}	Propagation Delay $\overline{MR}$ to Output	3.3	1.0	16.0	ns	
		5.0	1.0	11.5		

Note 5: Voltage Range 3.3 is 3.3V ±0.3V. Voltage Range 5.0 is 5.0V ±0.5V

AC Operating Requirements

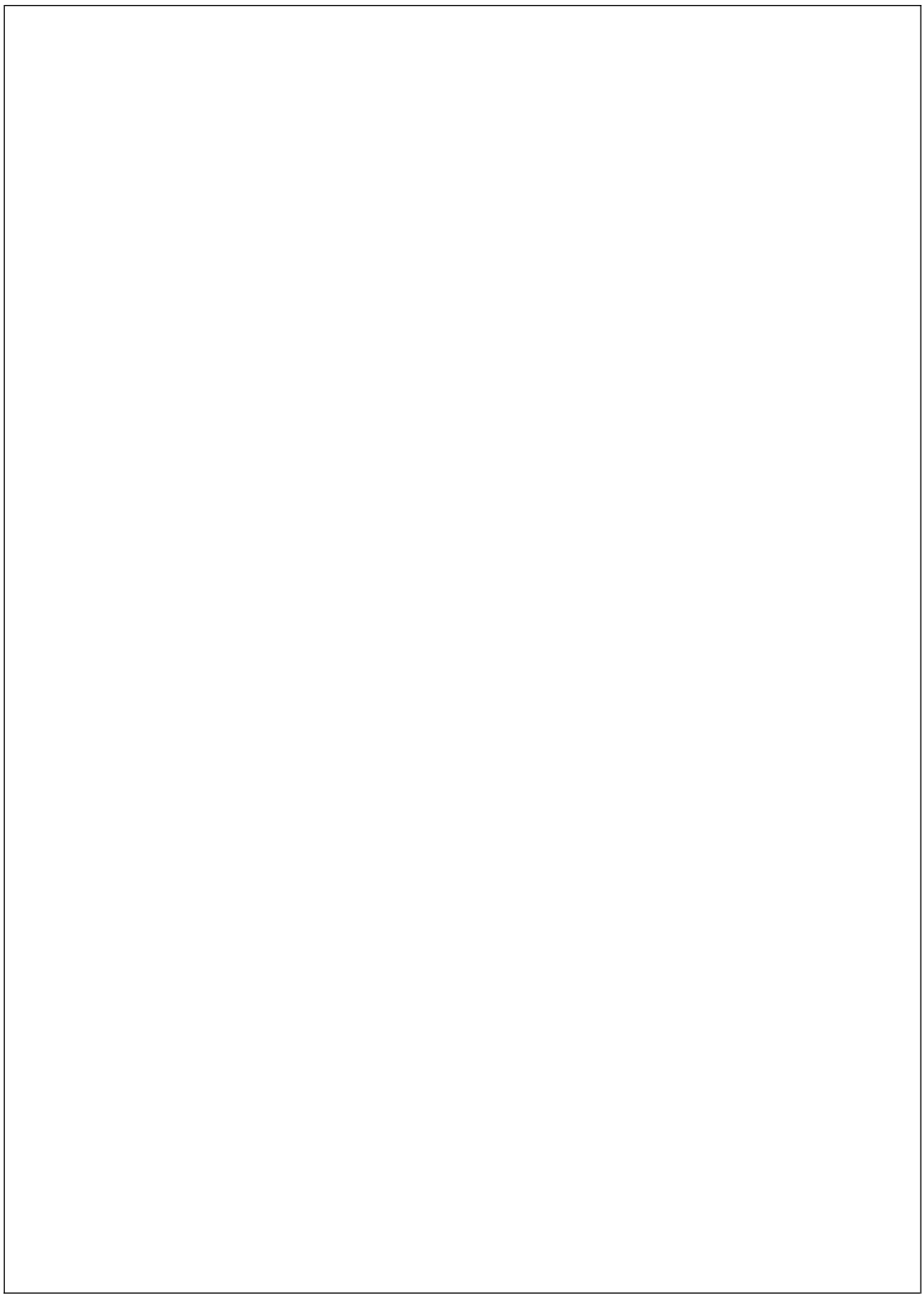
Symbol	Parameter	V_{CC} (V) (Note 6)	54AC T_A = −55°C to +125°C C_L = 50 pF Guaranteed Minimum	Units	Fig. No.
t_s	Setup Time, HIGH or LOW Data to CP	3.3	8.0	ns	
		5.0	5.0		
t_h	Hold Time, HIGH or LOW Data to CP	3.3	0	ns	
		5.0	1.0		
t_w	Clock Pulse Width HIGH or LOW	3.3	6.5	ns	
		5.0	5.0		
t_w	$\overline{MR}$ Pulse Width HIGH or LOW	3.3	10.0	ns	
		5.0	6.5		
t_{rec}	Recovery Time $\overline{MR}$ to CP	3.3	6.0	ns	
		5.0	4.0		

Note 6: Voltage Range 3.3 is 3.3V ±0.3V. Voltage Range 5.0 is 5.0V ±0.5V

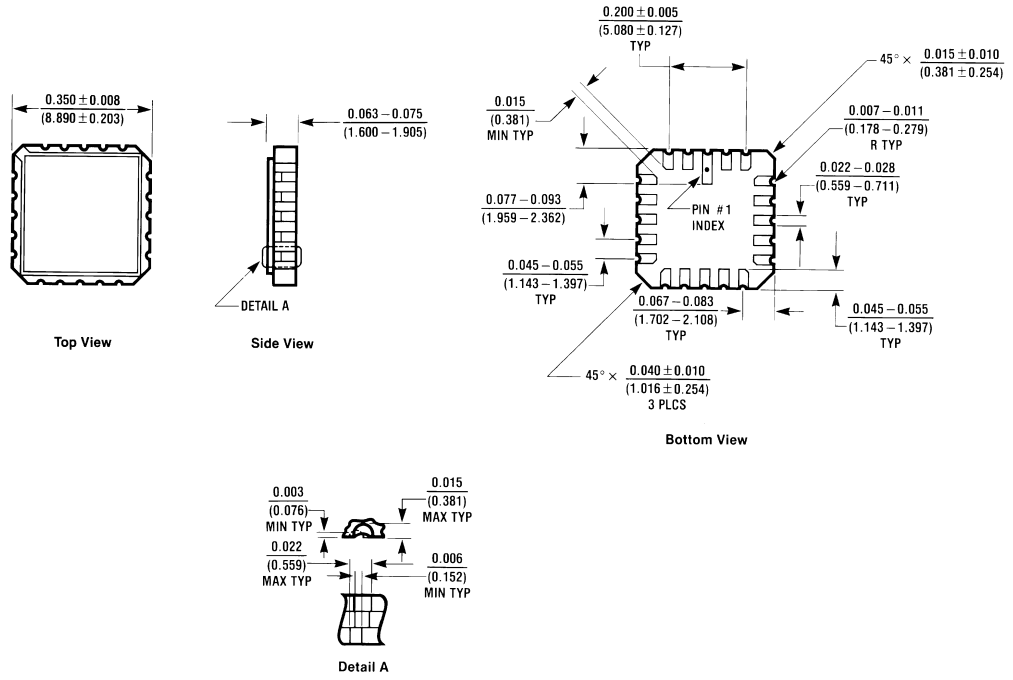
Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance	50.0	pF	V_{CC} = 5.0V

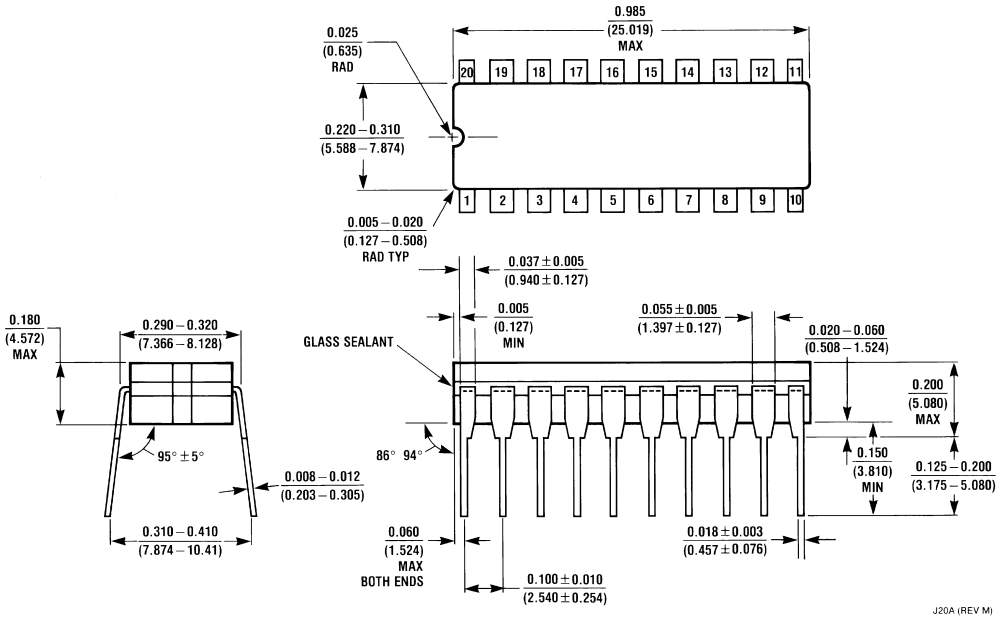
Book Extract End



Physical Dimensions inches (millimeters) unless otherwise noted

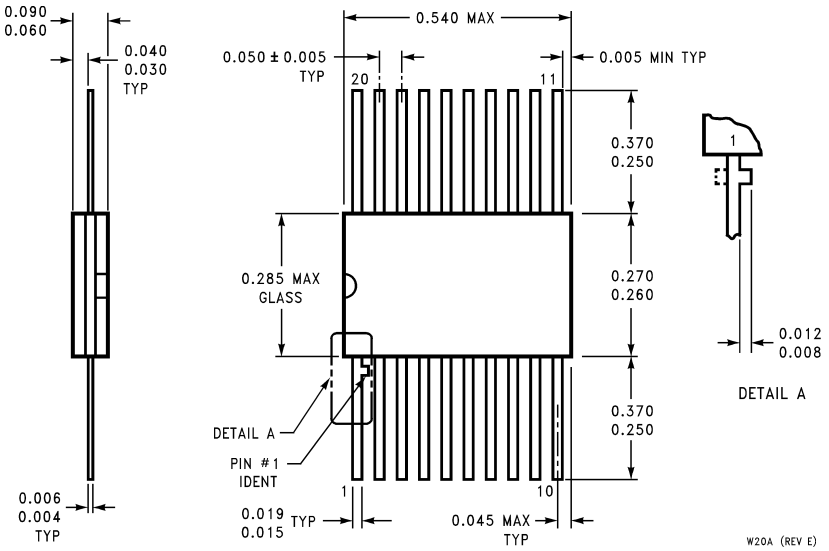


20 Terminal Ceramic Leadless Chip Carrier (L)
NS Package Number E20A



20 Lead Ceramic Dual-In-Line Package (D)
NS Package Number J20A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20 Lead Ceramic Flatpak (F)
NS Package Number W20A

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